



100V N-Channel Enhancement Mode MOSFET - ESD Protected

Voltage

100 V

Current

170 mA

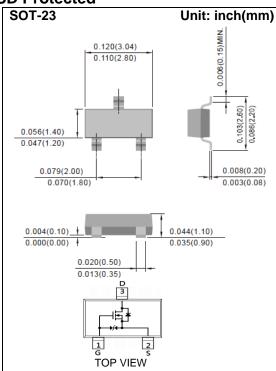
Features

- RDS(ON), VGS@10V, ID@170mA<6Ω
- RDS(ON), VGS@4.5V, ID@130mA<10Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 Package

• Terminals: Solderable per MIL-STD-750, Method 2026



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	170	mA
Pulsed Drain Current (Note 4)		I _{DM}	680	mA
Power Dissipation	T _a =25°C	P _D	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	ο°
Typical Thermal Resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	250	°C/W





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	100	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	1	1.7	2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =170mA	-	4	6	Ω		
		V _{GS} =4.5V, I _D =130mA	-	4.5	10			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V	-	-	1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 10	uA		
Dynamic (Note 5)								
Total Gate Charge	Q_g	V _{DS} =30V, I _D =170mA, V _{GS} =10V ^(Note 1,2)	-	1.8	-	nC		
Gate-Source Charge	Q_{gs}		-	0.4	-			
Gate-Drain Charge	Q_{gd}		-	0.3	-			
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	45	-	pF		
Output Capacitance	Coss		-	14	-			
Reverse Transfer Capacitance	Crss		-	7.8	-			
Turn-On Delay Time	td _(on))/ 00\/ L 470 ·· A	-	3.4	-	ns		
Turn-On Rise Time	tr	V_{DD} =30V, I_{D} =170mA, V_{GS} =10V, R_{G} =6 Ω (Note 1,2)	-	19	-			
Turn-Off Delay Time	td _(off)		-	8.2	-			
Turn-Off Fall Time	tf		-	20	-			
Drain-Source Diode								
Maximum Continuous Drain-Source				-	170	mA		
Diode Forward Current	I _S							
Diode Forward Voltage	V_{SD}	I _S =170mA, V _{GS} =0V	-	0.9	1.3	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

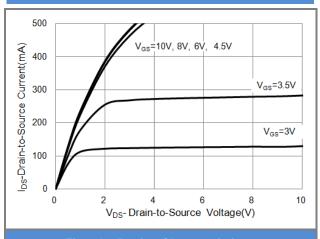


Fig.1 On-Region Characteristics

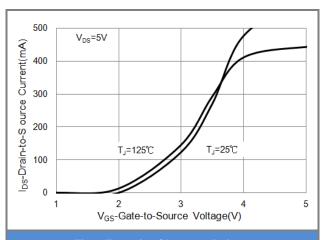


Fig.2 Transfer Characteristics

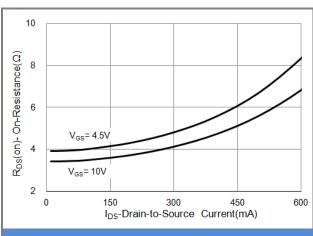


Fig.3 On-Resistance vs. Drain Current

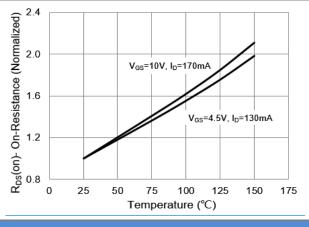


Fig.4 On-Resistance vs. Junction temperature

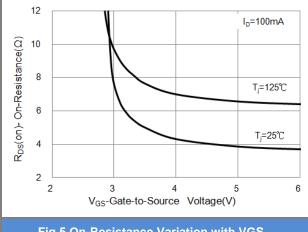


Fig.5 On-Resistance Variation with VGS.

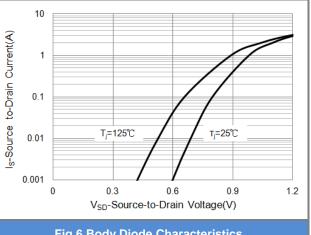


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

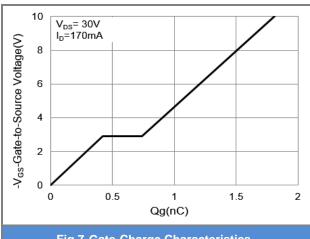


Fig.7 Gate-Charge Characteristics

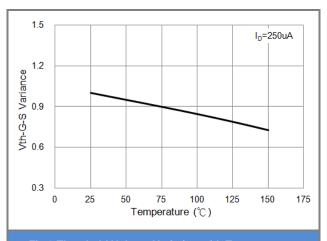


Fig.8 Threshold Voltage Variation with Temperature

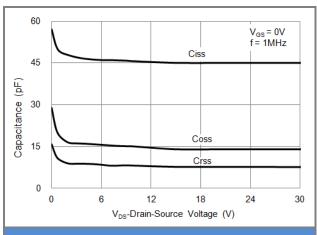


Fig.9 Capacitance vs. Drain-Source Voltage

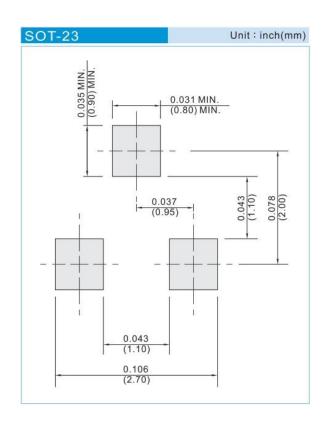




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing Type	Marking	Version
BSS123_R1_00001	SOT-23	3K pcs / 7" reel	A76	Halogen free
BSS123_R2_00001	SOT-23	12K pcs / 13" reel	A76	Halogen free

MOUNTING PAD LAYOUT







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